Diode Semiconductor Device - Page 1 of 1



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-	
	nclosure Material:
	Blass and metal
	Overall Length:
0	.570 inches
Ν	Iounting Method:
Т	erminal
F	eatures Provided:
H	lermetically sealed case
C	criticality Code Justification:
F	eat
S	emiconductor Material:
S	ilicon
۷	oltage Rating In Volts Per Characteristic:
5	.8 working peak reverse voltage, peak total value
Ν	Iaximum Operating Tempurature Per Measurement Point:
1	75.0 degrees celsius ambient air
S	pecial Features:
Ν	luclear hardness critical item
N	luclear Hardness Critical Feature:
F	lardened
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	shelf Life:
Ν	l/a
ι	Init Of Measure:
C	emilitarization:
Ν	lo
F	iig:
٨	.110a0